



BSC022N03S Information



For Reference Only

Part Number BSC022N03S

Manufacturer Infineon Technologies

Category Discrete Semiconductor Products

Transistors - FETs, MOSFETs - Single

Description MOSFET N-CH 30V 50A TDSON-8

Package 8-PowerTDFN

For the pricing/inventory/lead time, please contact

us

Website: https://www.heisener.com E-mail: salesdept@heisener.com



Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.









BSC022N03S Specifications

Manufacturer Part Number	BSC022N03S
Manufacturer	Infineon Technologies
Category	Discrete Semiconductor Products
	Transistors - FETs, MOSFETs - Single
Package	8-PowerTDFN
Series	OptiMOS?
FET Type	N-Channel
Technology	MOSFET (Metal Oxide)
Drain to Source Voltage (Vdss)	30V
Current - Continuous Drain (Id) @ 25°C	28A (Ta), 100A (Tc)
Drive Voltage (Max Rds On, Min Rds On)	4.5V, 10V
Vgs(th) (Max) @ Id	2V @ 100μA
Gate Charge (Qg) (Max) @ Vgs	58nC @ 5V
Input Capacitance (Ciss) (Max) @ Vds	7490pF @ 15V
Vgs (Max)	±20V
FET Feature	-
Power Dissipation (Max)	2.8W (Ta), 104W (Tc)
Rds On (Max) @ Id, Vgs	2.2 mOhm @ 50A, 10V
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Supplier Device Package	PG-TDSON-8
Package / Case	8-PowerTDFN
	Report errors?

BSC022N03S Guarantees



Quality Guarantees

We provide 90 days warranty. *

If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.



Service Guarantees

We guarantee 100% customer satisfaction.

Our experienced sales team and tech support team back our services to satisfy all our customers.

BSC022N03S Payment Methods



















BSC022N03S Shipping Methods













If you have any question about BSC022N03S, please do not hesitate to contact us!

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